

## Complementary silicon power transistors

#### **Features**

- STMicroelectronics preferred salestypes
- Complementary NPN PNP devices

### **Applications**

■ Linear and switching industrial equipment

### **Description**

The MJE340 is a silicon planar NPN transistor intended for use in medium power linear and switching applications. It is mounted in SOT-32.

The complementary PNP type is MJE350.

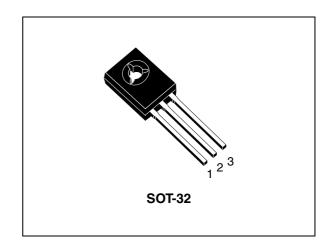


Figure 1. Internal schematic diagram

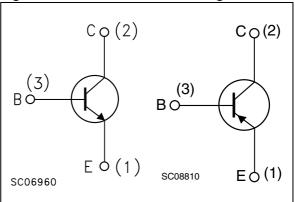


Table 1. Device summary

Order code	Marking	Polarity	Package	Packaging
MJE340	MJE340	NPN	SOT-32	Tube
MJE350	MJE350	PNP	SOT-32	Tube

Electrical ratings MJE340, MJE350

# 1 Electrical ratings

Table 2. Absolute maximum ratings

		Value		
Symbol	Parameter	MJE340 (NPN)	Unit	
		MJE350 (PNP)		
V <sub>CBO</sub>	Collector-base voltage (I <sub>E</sub> = 0)	300	V	
V <sub>CEO</sub>	Collector-emitter voltage (I <sub>B</sub> = 0)	300	V	
V <sub>EBO</sub>	Base-emitter voltage ( $I_C = 0$ )	3	V	
I <sub>C</sub>	Collector current	0.5	Α	
P <sub>TOT</sub>	Total dissipation at T <sub>c</sub> ≤ 25 °C	20.8	W	
T <sub>stg</sub>	Storage temperature	-65 to 150	°C	
T <sub>J</sub>	Max operating junction temperature	150	]	

Note: for PNP type voltage and current values are negative.

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R <sub>thJC</sub>	Thermal resistance junction-case max	6.0	°C/W

## 2 Electrical characteristics

 $T_{case}$  = 25 °C unless otherwise specified.

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I <sub>CBO</sub>	Collector cut-off current (I <sub>E</sub> = 0)	V <sub>CB</sub> = 300 V			100	μΑ
I <sub>EBO</sub>	Emitter cut-off current (I <sub>C</sub> = 0)	V <sub>EB</sub> = 3 V			100	μΑ
V <sub>CEO(sus)</sub> <sup>(1)</sup>	Collector-emitter sustaining voltage $(I_B = 0)$	I <sub>C</sub> = 1 mA	300			٧
V <sub>BE(on)</sub>	Emitter-base on voltage $(I_C = 0)$	$I_C = 50 \text{ mA}$ $V_{CE} = 10 \text{ V}$			1	V
V <sub>CE(sat)</sub> (1)	Collector-emitter saturation voltage	$I_C = 100 \text{ mA}$ $I_B = 10 \text{ mA}$			0.5	V
h <sub>FE</sub>	DC current gain	$I_C = 50 \text{ mA}$ $V_{CE} = 10 \text{ V}$	30		240	

<sup>1.</sup> Pulse test: pulse duration = 300  $\mu$ s, duty cycle  $\leq$  2 %.

Note: for PNP type voltage and current values are negative.

**Electrical characteristics** MJE340, MJE350

#### 2.1 **Electrical characteristics (curves)**

Figure 2. Safe operating area I<sub>C</sub> (A) I<sub>C</sub> MAX PULSED PULSE OPERATION \* 100 100 μs 10<sup>-1</sup> 10-2 For single non repetitive pulse 10-3 10<sup>0</sup> 8 10<sup>2</sup> V<sub>CE</sub> (V)

Figure 3. **Derating curve** 

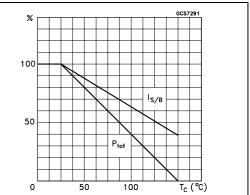
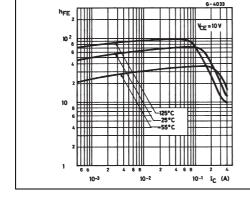


Figure 4. DC current gain (NPN type)

Figure 5. DC current gain (PNP type)

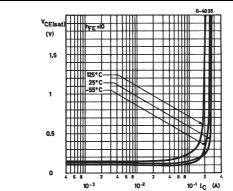


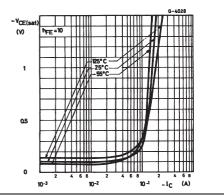
50 -I<sub>C</sub> (A)

Figure 6. **Collector-emitter saturation** voltage (NPN type)

(V)

Figure 7. **Base-emitter saturation** voltage (PNP type)





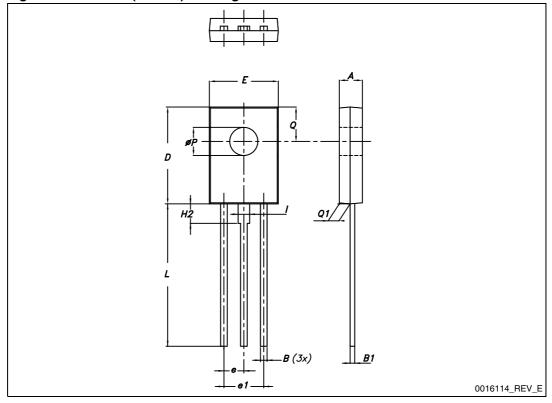
## 3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <a href="https://www.st.com">www.st.com</a>. ECOPACK<sup>®</sup> is an ST trademark.

Table 5. SOT-32 (TO-126) mechanical data

Dim.		mm.	
	Min.	Тур.	Max.
Α	2.40		2.90
В	0.64		0.88
B1	0.39		0.63
D	10.50	11.05	
E	7.40		7.80
е	2.04	2.29	2.54
e1	4.07	4.58	5.08
L	15.30		16
ØP	2.90		3.20
Q		3.80	
Q1	1		1.52
H2		2.15	
I		1.27	

Figure 8. SOT-32 (TO-126) drawing



MJE340, MJE350 Revision history

# 4 Revision history

Table 6. Document revision history

Date	Revision	Changes
05-Apr-2011	5	Minor text changes
10-Nov-2011	6	Added: V <sub>CBO</sub> in <i>Table 2</i> , V <sub>CE(sat)</sub> and V <sub>BE(on)</sub> in <i>Table 4</i>

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